Product data sheet

1. General description

PNP high-voltage transistor in a SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low current (max. 100 mA)
- High voltage (max. 100 V)

3. Applications

- High-voltage general purpose
- Switching applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-100	V
I _C	collector current		-	-	-100	mA
h _{FE}	DC current gain	V _{CE} = -1 V; I _C = -10 mA; T _{amb} = 25 °C	30	-	-	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	Е	emitter		C
3	С	collector		В——
			1 2	E sym132
			SOT23	



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6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BSS63		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
BSS63	BM%

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-110	V
V _{CEO}	collector-emitter voltage	open base		-	-100	V
V_{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current			-	-100	mA
I _{BM}	peak base current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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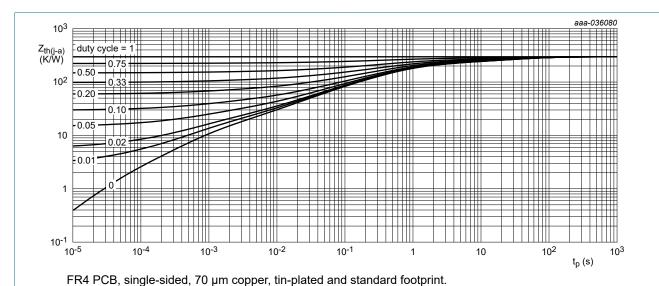
PNP high-voltage transistor

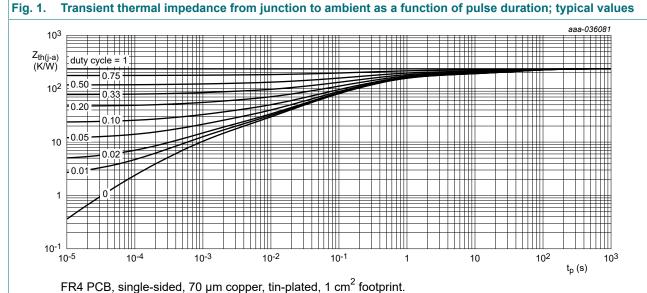
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.





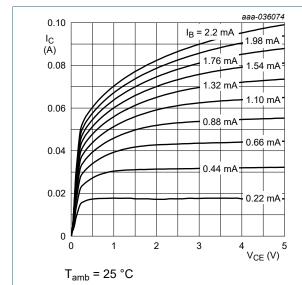
Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 2.

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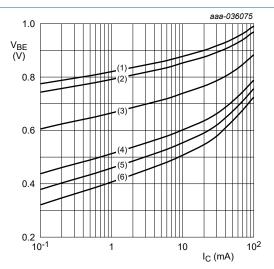
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -90 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -90 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -6 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -1 V; I_{C} = -10 mA; T_{amb} = 25 °C	30	-	-	
		V_{CE} = -1 V; I_{C} = -25 mA; T_{amb} = 25 °C	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -25 \text{ mA}; I_B = -2.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	-250	mV
V _{BEsat}	base-emitter saturation voltage		-	-	-900	mV
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -25 mA; f = 100 MHz; T_{amb} = 25 °C	50	85	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	3	-	pF



Collector current as a function of collector-Fig. 3. emitter voltage; typical values



 V_{CE} = 1 V; T_{amb} = 25 °C

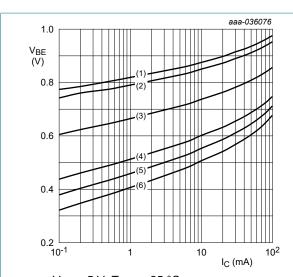
(1) $T_{amb} = -55^{\circ}C$ (2) $T_{amb} = -40^{\circ}C$

(2) $T_{amb} = 40 \text{ C}$ (3) $T_{amb} = 25^{\circ}\text{C}$ (4) $T_{amb} = 100^{\circ}\text{C}$ (5) $T_{amb} = 125^{\circ}\text{C}$ (6) $T_{amb} = 150^{\circ}\text{C}$

Fig. 4. Base-emitter voltage as a function of collector current; typical values

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$$V_{CE} = 5 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$$

 $V_{CE} = 1 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$
(1) $T_{amb} = -55 ^{\circ}\text{C}$

$$V_{CE} = 1 \text{ V}; T_{amb} = 25 \text{ °C}$$

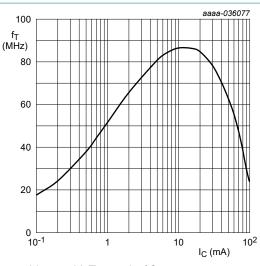
(1)
$$T_{amb} = -55^{\circ}C$$

(2)
$$T_{amb} = -40^{\circ}C$$

(3)
$$T_{amb} = 25^{\circ}C$$

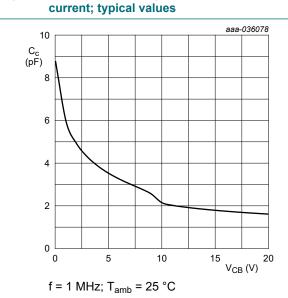
$$(4) T_{amb} = 100^{\circ} C$$

Base-emitter voltage as a function of collector Fig. 5.

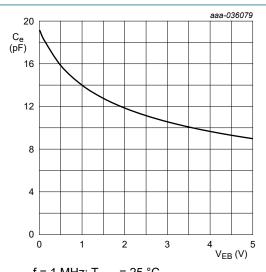


 V_{CE} = 5 V; T_{amb} = 25 °C

Fig. 6. Transition frequency as a function of collector current; typical values



Collector capacitance as a function of collector- Fig. 8. Fig. 7. base voltage; typical values

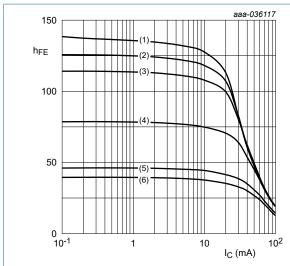


 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$

Emitter capacitance as a function of emitterbase voltage; typical values

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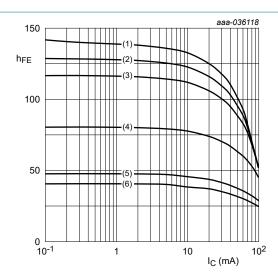
 $V_{CE} = 1 V$

 $(1) T_{amb} = 150 °C$

(2) $T_{amb} = 125 \, ^{\circ}C$

(3) $T_{amb} = 125 \text{ C}$ (3) $T_{amb} = 100 \text{ °C}$ (4) $T_{amb} = 25 \text{ °C}$ (5) $T_{amb} = -40 \text{ °C}$ (6) $T_{amb} = -55 \text{ °C}$

DC current gain as a function of collector Fig. 9. current; typical values

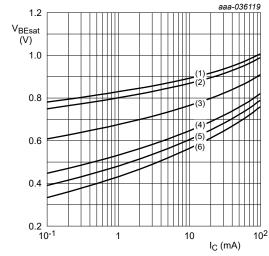


V_{CE} = 5 V (1) T_{amb} = 150 °C

(2) T_{amb} = 125 °C

(2) $T_{amb} = 120^{\circ} \text{ C}$ (3) $T_{amb} = 100^{\circ} \text{ C}$ (4) $T_{amb} = 25^{\circ} \text{ C}$ (5) $T_{amb} = -40^{\circ} \text{ C}$ (6) $T_{amb} = -55^{\circ} \text{ C}$

Fig. 10. DC current gain as a function of collector current; typical values



 $I_C/I_B = 10$

 $(1) T_{amb} = -55 °C$

(2) $T_{amb} = -40 \, ^{\circ}C$

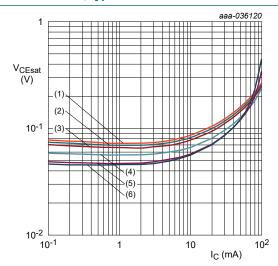
(3) $T_{amb} = 25 \, ^{\circ}C$

(4) T_{amb} = 100 °C

 $(5) T_{amb} = 125 °C$

(6) T_{amb} = 150 °C

Fig. 11. Base-emitter saturation voltage as a function of Fig. 12. Collector-emitter saturation voltage as a collector current; typical values



 $I_{\rm C}/I_{\rm B}=10$

(1) $T_{amb} = 150 \, ^{\circ}C$

(2) $T_{amb} = 125 \, ^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$

(4) $T_{amb} = 25 \, ^{\circ}C$

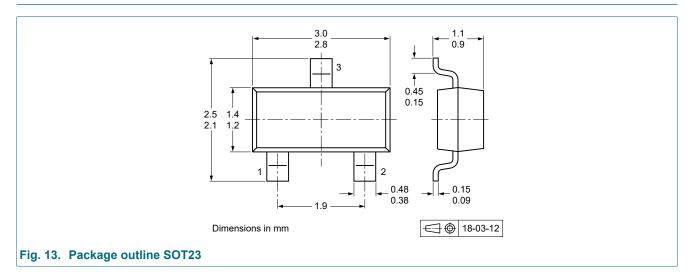
 $(5) T_{amb} = -40 °C$

(6) $T_{amb} = -55 \, ^{\circ}C$

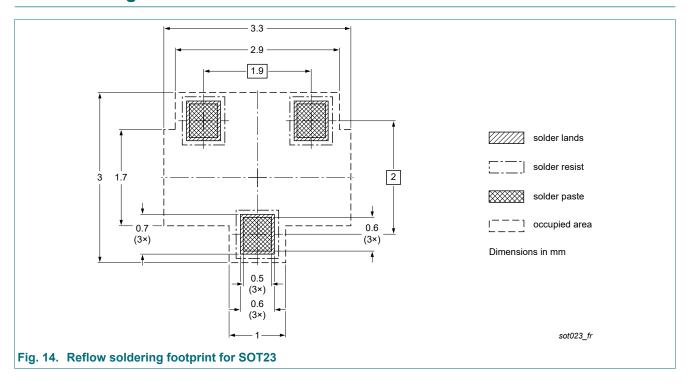
function of collector current; typical values

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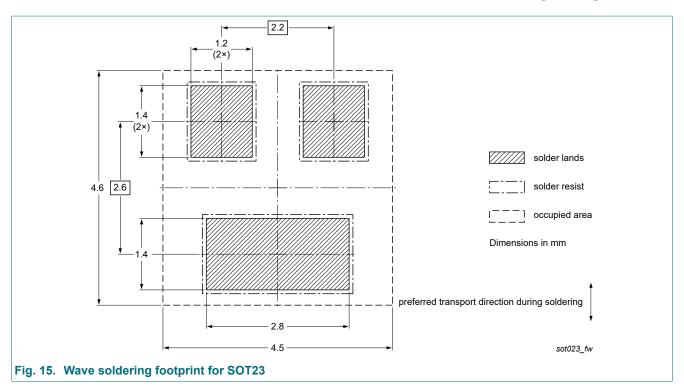
11. Package outline



12. Soldering



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13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BSS63 v.3	20230701	Product data sheet	-	BSS63 v.2
Modifications:	Nexperia. • Legal texts hav • Thermal chara	•	company name where : Graphs added	
BSS63 v.2	20040116	Product data sheet	-	BSS63 v.1
BSS63 v.1	19990415	Product data sheet	-	-

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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